

TLV709 150-mA, 30-V, 3.2- μ A Quiescent Current, Low-Dropout Linear Regulator

1 Features

- Input voltage range: 2.5 V to 30 V
- Available output voltage options:
 - Fixed: 1.2 V to 5 V
 - Adjustable: 1.2 V to 28 V
- Output current: Up to 150 mA
- Very-low I_Q : 3.2 μ A at 150-mA load current
- Stable with output capacitor $\geq 0.47 \mu$ F
- Overcurrent protection
- Packages:
 - 4-pin SOT-89 (PK) (fixed configuration only)
 - 5-pin SOT-23 (DBV) (both fixed and adjustable configurations)
- Operating junction temperature: -40°C to $+125^\circ\text{C}$

2 Applications

- Home and building automation
- Retail automation and payment
- Grid infrastructure
- Medical applications
- Lighting applications

3 Description

The TLV709 low-dropout (LDO) linear voltage regulator is a low quiescent current device that offers the benefits of a wide input voltage range and low-power operation in miniaturized packaging. The TLV709 is optimized to power microcontrollers and other low power loads for battery-powered applications.

The TLV709 LDO supports a low dropout of typically 600 mV at 100 mA of load current. The low quiescent current (3.2 μ A typically) does not vary across the entire range of output load current (0 mA to 150 mA). The TLV709 also features an internal soft-start to lower the inrush current during start-up. The built-in overcurrent limit protection helps protect the regulator in the event of a load short or fault condition.

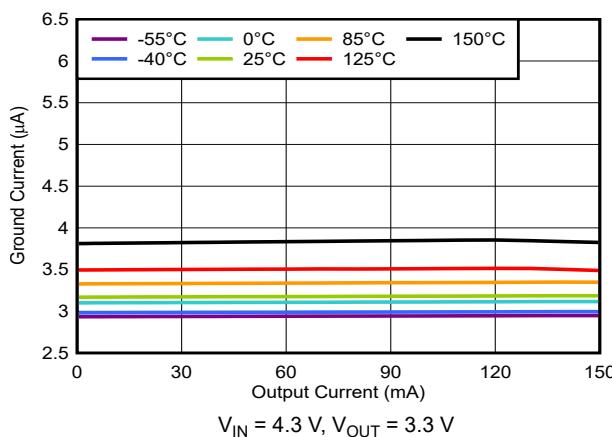
The TLV709 is available in a 2.90-mm \times 1.60-mm, 5-pin SOT-23 (DBV) package for fixed and adjustable outputs, and in a 4.50-mm \times 2.5-mm, 3-pin SOT-89 (PK) package for fixed outputs.

Package Information

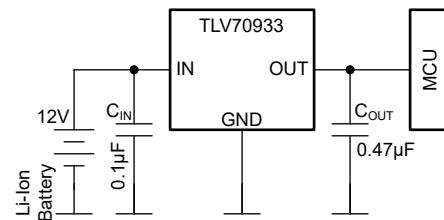
| PART NUMBER | PACKAGE ⁽¹⁾ | PACKAGE SIZE ⁽²⁾ |
|-------------|------------------------|-----------------------------|
| TLV709 | DBV (SOT-23, 5) | 2.9 mm \times 2.8 mm |
| | PK (SOT-89, 3) | 4.5 mm \times 4.095 mm |

(1) For all available packages, see the orderable addendum at the end of the data sheet.

(2) The package size (length \times width) is a nominal value and includes pins, where applicable.



Quiescent Current vs Load Current



Typical Application



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| Changes from Revision A (May 2023) to Revision B (June 2023) | Page |
|---|-------------|
| • Changed numbering of pins for the PK package..... | 3 |
| <hr/> | |
| Changes from Revision * (February 2023) to Revision A (May 2023) | Page |
| • Changed document status from <i>Advance Information</i> to <i>Production Data</i> | 1 |

5 Pin Configuration and Functions

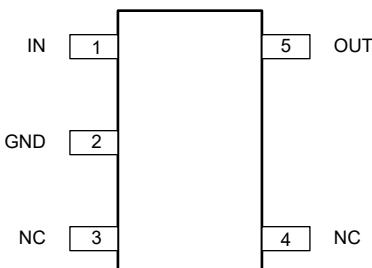


Figure 5-1. DBV Package (Fixed), 5-Pin SOT-23 (Top View)

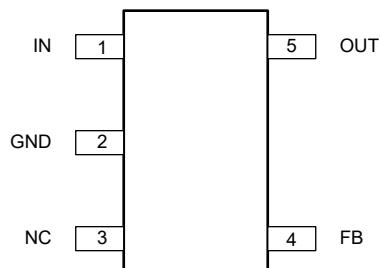


Figure 5-2. DBV Package (Adjustable), 5-Pin SOT-23 (Top View)

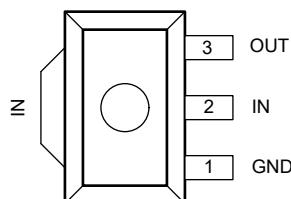


Figure 5-3. TLV709xxPKR PK Package (IN Tab), 3-Pin SOT-89 (Top View)

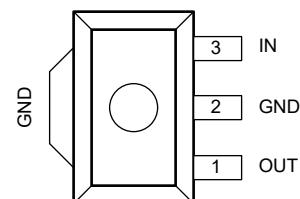


Figure 5-4. TLV709AxxPKR PK Package (GND Tab), 3-Pin SOT-89 (Top View)

Table 5-1. Pin Functions

| PIN | | | | | TYPE | DESCRIPTION |
|------|-------------|-----------|-------------|--------------|------|---|
| NAME | DBV (Fixed) | DBV (Adj) | PK (IN Tab) | PK (GND Tab) | | |
| GND | 2 | 2 | 1 | 2, tab | — | Ground pin. |
| IN | 1 | 1 | 2, tab | 3 | I | Input supply pin. See the Recommended Operating Conditions table and the Input and Output Capacitor Requirements section for more information. |
| OUT | 5 | 5 | 3 | 1 | O | Output of the regulator. See the Recommended Operating Conditions table and the Input and Output Capacitor Requirements section for more information. |
| FB | — | 4 | — | — | I | In the adjustable configuration, this pin sets the output voltage with the help of a feedback divider. |
| NC | 3, 4 | 3 | — | — | — | Not internally connected. This pin can be left open or tied to ground for improved thermal performance. |

6 Specifications

6.1 Absolute Maximum Ratings

over operating temperature range (unless otherwise noted)⁽¹⁾ ⁽²⁾

| | | MIN | MAX | UNIT |
|-------------|--|--------------------|--|------|
| Voltage | V_{IN} | -0.3 | 30 | V |
| | V_{OUT} (for fixed device only) | -0.3 | $2 \times V_{OUT(typ)}$ or $V_{IN} + 0.3$ or 5.5 (whichever is lower) | |
| | V_{OUT} (for adjustable device only) | -0.3 | $V_{IN} + 0.3$ | |
| | V_{FB} | -0.3 | 2.4 | |
| Current | Peak output current | Internally limited | | |
| Temperature | Junction, T_J | -40 | 150 | °C |
| | Storage, T_{stg} | -65 | 150 | |

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to the ground terminal.

6.2 ESD Ratings

| | | | VALUE | UNIT |
|-------------|-------------------------|--|-------|------|
| $V_{(ESD)}$ | Electrostatic discharge | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾ | ±2000 | V |
| | | Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾ | ±500 | |

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

| | | MIN | NOM | MAX | UNIT |
|-----------|---|-------|-----|-----|---------|
| V_{IN} | Input supply voltage | 2.5 | 30 | | |
| V_{OUT} | Output voltage (for adjustable device only) | 1.205 | 28 | | V |
| | Output voltage (for fixed device only) | 1.205 | 5.0 | | |
| I_{OUT} | Output current | 0 | 150 | | mA |
| C_{IN} | Input capacitor ⁽²⁾ | 0.47 | | | μ F |
| C_{OUT} | Output capacitor ⁽³⁾ | 1 | | | |
| T_J | Operating junction temperature | -40 | 125 | | °C |

(1) All voltages are with respect to GND.

(2) An input capacitor is not required for LDO stability. However, an input capacitance with an effective value of 0.1 μ F minimum is recommended to counteract the effect of source resistance and inductance, which may in some cases cause symptoms of system-level instability such as ringing or oscillation, especially in the presence of load transients.

(3) All capacitor values listed are the nominal value and the effective capacitance is assumed to derate to 50% of the nominal capacitor value.

6.4 Thermal Information

| THERMAL METRIC ⁽¹⁾ | | TLV709 ⁽²⁾ | | UNIT |
|-------------------------------|--|-----------------------|----------------|------|
| | | DBV [SOT-23] | PK [SOT-89] | |
| | | 5 PINS | 4 PINS | |
| R _{θJA} | Junction-to-ambient thermal resistance | 195.7 | 131.7 | °C/W |
| R _{θJC(top)} | Junction-to-case (top) thermal resistance | 88.2 | 65.8 | °C/W |
| R _{θJB} | Junction-to-board thermal resistance | 40.7 | 32.4 | °C/W |
| Ψ _{JT} | Junction-to-top characterization parameter | 11.2 | 69.8 | °C/W |
| Ψ _{JB} | Junction-to-board characterization parameter | 40.5 | 96.2 | °C/W |

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC package thermal metrics](#) application report.
- (2) Thermal performance results are based on the JEDEC standard of 2s2p PCB configuration. These thermal metric parameters can be further improved by 35-55% based on thermally optimized PCB layout designs. See the analysis of the [Impact of board layout on LDO thermal performance](#) application report.

6.5 Electrical Characteristics

over operating junction temperature range ($T_J = -40^\circ\text{C}$ to 125°C), $V_{IN} = V_{OUT(nom)} + 1 \text{ V}$, $I_{OUT} = 100 \mu\text{A}$, and $C_{OUT} = 1 \mu\text{F}$, unless otherwise noted; typical values are at $T_J = 25^\circ\text{C}$. (1)

| PARAMETER | | TEST CONDITIONS | | MIN | TYP | MAX | UNIT | |
|---------------------------------------|--|--|--|-------|-------|------|------------------|--|
| V_{IN} | Input voltage (2) | $I_O = 10 \text{ mA}$ | | 2.5 | 30 | | V | |
| | | $10 \text{ mA} \leq I_O < 50 \text{ mA}$ | | 3.0 | 30 | | | |
| | | $50 \text{ mA} \leq I_O \leq 150 \text{ mA}$ | | 3.5 | 30 | | | |
| V_{OUT} | Output voltage range (TLV70901) | | | 1.205 | 28 | | V | |
| V_{FB} | Internal reference(2) | | | 1.12 | 1.205 | 1.24 | | |
| V_{OUT} (5) | Output voltage accuracy (1) (2) (3) | Over V_{IN} , I_{OUT} , and temp | $V_{OUT} + 1.0 \text{ V} \leq V_{IN} \leq 30 \text{ V}$ $100 \mu\text{A} \leq I_{OUT} \leq 150 \text{ mA}$ | -4 | 4 | | % | |
| | | Over V_{IN} , temp and $I_{OUT} = 10 \text{ mA}$ | $V_{OUT} + 1.0 \text{ V} \leq V_{IN} \leq 30 \text{ V}$ $I_{OUT} = 10 \text{ mA}$ | -4 | 4 | | | |
| | | Over V_{IN} , I_{OUT} , and $T_J = 25^\circ\text{C}$ | $V_{OUT} + 1 \text{ V} \leq V_{IN} \leq 30 \text{ V}$ $100 \mu\text{A} \leq I_{OUT} \leq 150 \text{ mA}$ and $T_J = 25^\circ\text{C}$ | -2 | 2 | | | |
| I_{GND} | Ground pin current (1) (4) | $I_{OUT} = 0 \text{ mA}$ | | 3.2 | | | μA | |
| | | $100 \mu\text{A} \leq I_{OUT} \leq 150 \text{ mA}$, $T_J = -40^\circ\text{C}$ to 85°C | | 3.2 | 4.2 | | | |
| | | $100 \mu\text{A} \leq I_{OUT} \leq 150 \text{ mA}$ | | 3.2 | 4.8 | | | |
| | | $100 \mu\text{A} \leq I_{OUT} \leq 150 \text{ mA}$, $V_{IN} = 30 \text{ V}$ | | | 10 | | | |
| ΔV_{OUT} (ΔI_{OUT}) | Load regulation (1) | $V_{OUT} \geq 3.3 \text{ V}$, $100 \mu\text{A} < I_{OUT} < 10 \text{ mA}$ | | 1 | | | %/ A | |
| | | $V_{OUT} \geq 3.3 \text{ V}$, $100 \mu\text{A} < I_{OUT} < 50 \text{ mA}$ | | 1 | | | | |
| | | $V_{OUT} \geq 3.3 \text{ V}$, $100 \mu\text{A} < I_{OUT} < 150 \text{ mA}$ | | 1 | 2.5 | | | |
| ΔV_{OUT} (ΔV_{IN}) | Line regulation (1) | | $V_{OUT(nom)} + 1 \text{ V} \leq V_{IN} \leq 30 \text{ V}$ | 0.02 | 0.05 | | %/ V | |
| V_n | Output noise voltage | $BW = 10 \text{ Hz}$ to 100 kHz , $C_{OUT} = 10 \mu\text{F}$ | $I_{OUT} = 1 \text{ mA}$ | 487 | | | μVRms | |
| | | | $I_{OUT} = 50 \text{ mA}$ | 577 | | | | |
| I_{CL} | Output current limit | | $V_{OUT} = 0 \text{ V}$, $V_{IN} \geq 3.5 \text{ V}$ | 160 | 1000 | | mA | |
| | | | $V_{OUT} = 0 \text{ V}$, $V_{IN} < 3.5 \text{ V}$ | 90 | 1000 | | mA | |
| PSRR | Power-supply ripple rejection | | $f = 100 \text{ kHz}$, $C_{OUT} = 10 \mu\text{F}$ | 60 | | | dB | |
| V_{DO} | Dropout voltage | $V_{IN} = V_{OUT(nom)} - 0.1 \text{ V}$, $I_{OUT} = 10 \text{ mA}$ | | 75 | 150 | | mV | |
| | | $V_{IN} = V_{OUT(nom)} - 0.1 \text{ V}$, $I_{OUT} = 50 \text{ mA}$ | | 400 | | | | |
| | | $V_{IN} = V_{OUT(nom)} - 0.1 \text{ V}$, $I_{OUT} = 150 \text{ mA}$ | | 1000 | 1600 | | | |

- (1) TLV709 is stable and functional over the entire load current range from 0 mA to I_{CL} .
- (2) Minimum $V_{IN} = V_{OUT} + 1 \text{ V}$ or the value shown for *Input voltage* in this table, whichever is greater.
- (3) For adjustable device, output accuracy excludes the tolerance and mismatch associated with external resistors used for setting up the output voltage.
- (4) See [Leakage null control circuit](#). The TLV709 family employs a leakage null control circuit. This circuit is active only if output current is less than pass FET leakage current. The circuit is typically active when output load is less than 5 μA , V_{IN} is greater than 18 V, and die temperature is greater than 100°C .
- (5) Minimum V_{IN} used for $I_{OUT} = 150 \text{ mA}$ is $V_{OUT} + 1.6 \text{ V}$.

6.6 Typical Characteristics

at operating temperature $T_J = 25^\circ\text{C}$, $V_{IN} = V_{OUT(NOM)} + 1.0 \text{ V}$ or 2.5 V (whichever is greater), $V_{OUT(\text{typ})} = 3.3 \text{ V}$, $I_{OUT} = 1 \text{ mA}$, $C_{IN} = 1 \mu\text{F}$, and $C_{OUT} = 1 \mu\text{F}$ (unless otherwise noted)

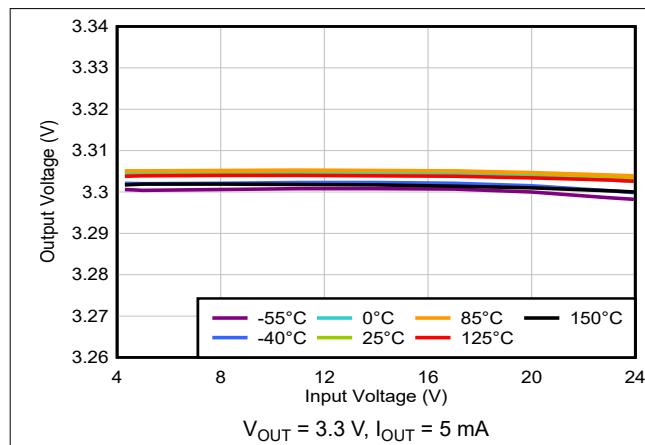


Figure 6-1. Line Regulation

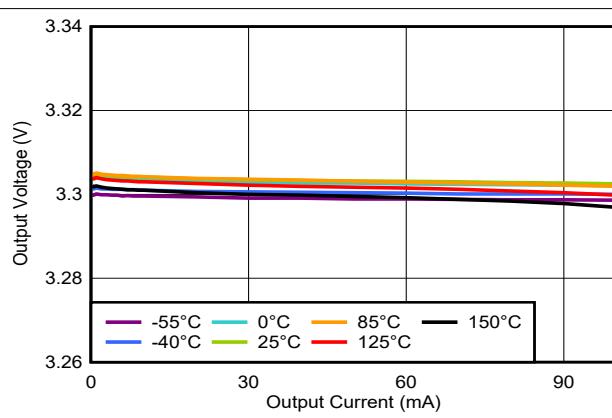


Figure 6-2. Load Regulation

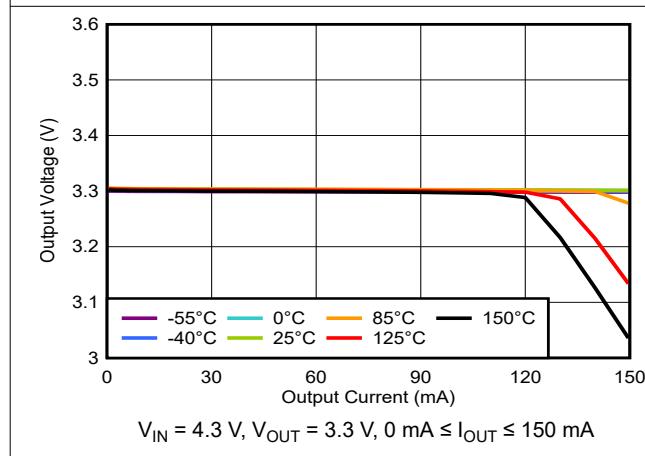


Figure 6-3. Load Regulation

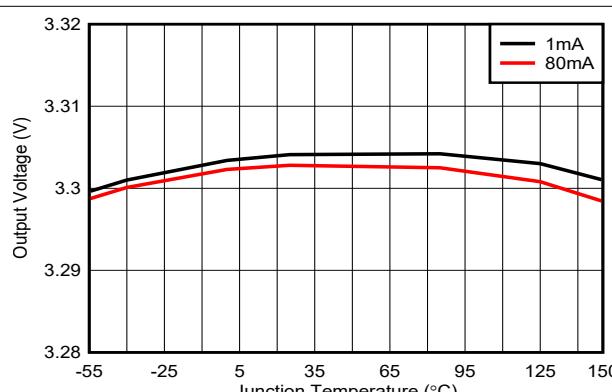


Figure 6-4. V_{OUT} vs Temperature and I_{OUT}

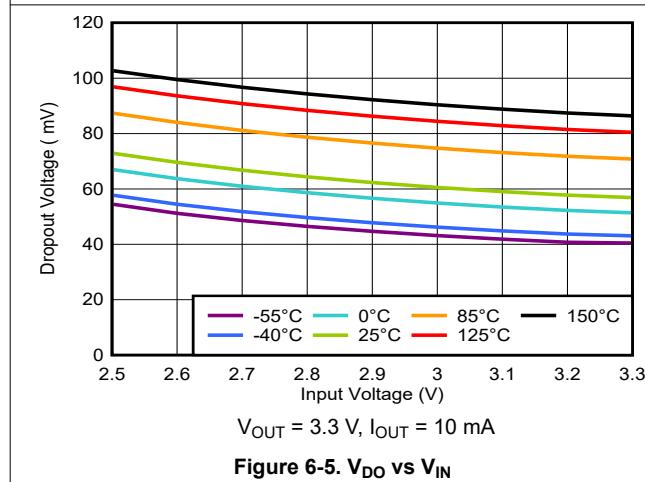


Figure 6-5. V_{DO} vs V_{IN}

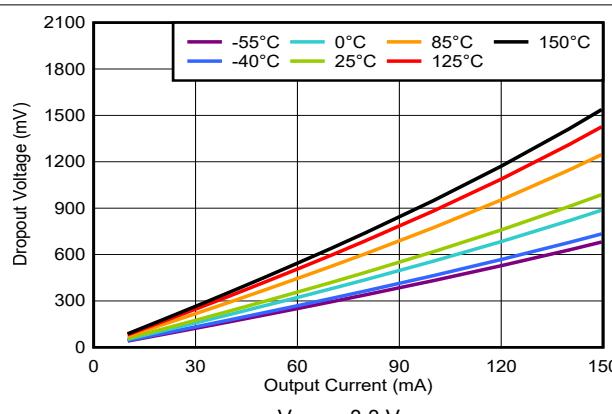
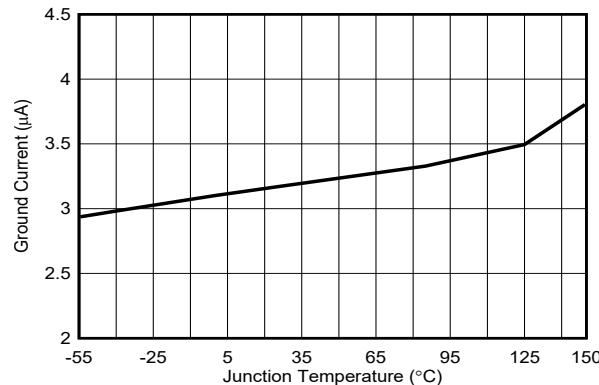


Figure 6-6. V_{DO} vs I_{OUT}

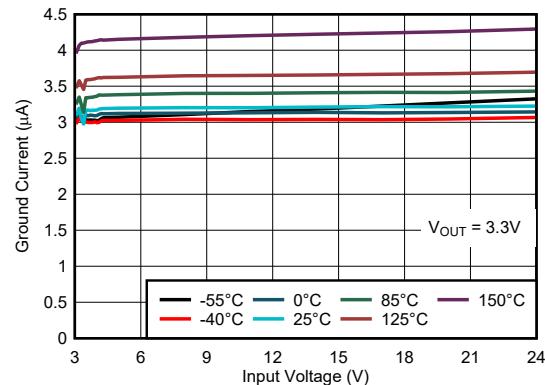
6.6 Typical Characteristics (continued)

at operating temperature $T_J = 25^\circ\text{C}$, $V_{IN} = V_{OUT(NOM)} + 1.0 \text{ V}$ or 2.5 V (whichever is greater), $V_{OUT(\text{typ})} = 3.3 \text{ V}$, $I_{OUT} = 1 \text{ mA}$, $C_{IN} = 1 \mu\text{F}$, and $C_{OUT} = 1 \mu\text{F}$ (unless otherwise noted)



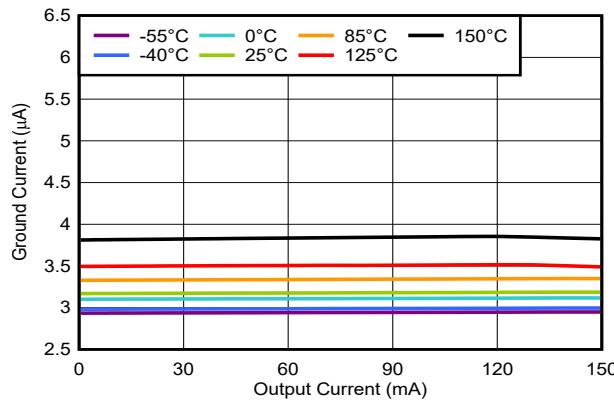
$V_{IN} = 4.3 \text{ V}$, $V_{OUT} = 3.3 \text{ V}$, $I_{OUT} = 0 \text{ mA}$, $C_{OUT} = 1 \mu\text{F}$

Figure 6-7. Ground Current vs Temperature



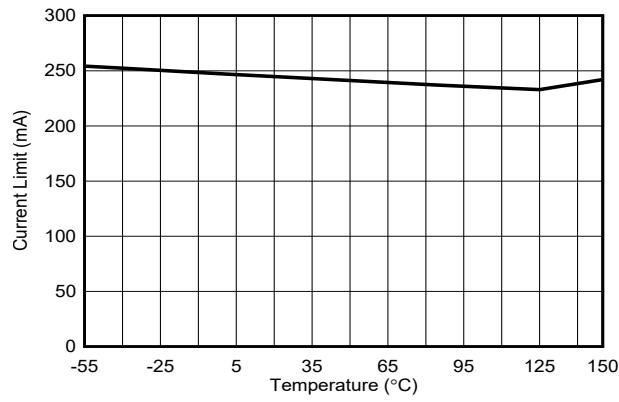
$V_{OUT} = 3.3 \text{ V}$, $I_{OUT} = 0 \text{ mA}$, $C_{OUT} = 1 \mu\text{F}$

Figure 6-8. Ground Current vs V_{IN}



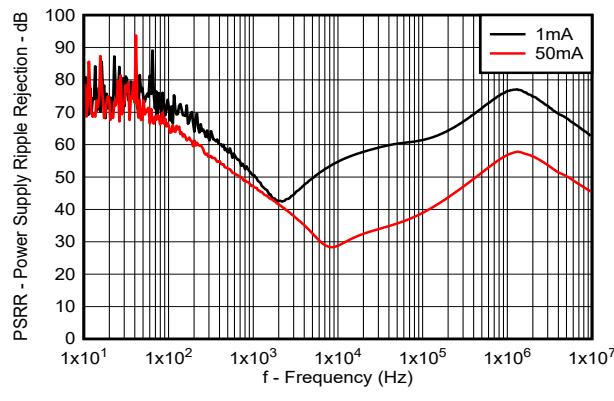
$V_{IN} = 4.3 \text{ V}$, $V_{OUT} = 3.3 \text{ V}$, $C_{OUT} = 1 \mu\text{F}$

Figure 6-9. Ground Current vs I_{OUT}



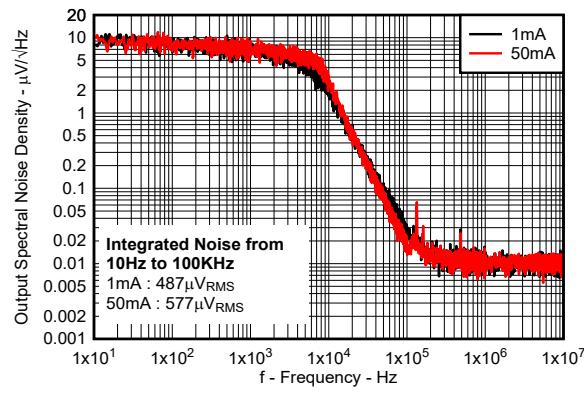
$V_{IN} = 4.8 \text{ V}$, $V_{OUT} = 3.3 \text{ V}$

Figure 6-10. I_{CL} vs Temperature



$V_{IN} = 4.3 \text{ V}$, $V_{OUT} = 3.3 \text{ V}$, $C_{OUT} = 10 \mu\text{F}$

Figure 6-11. PSRR vs Frequency



$V_{IN} = 4.3 \text{ V}$, $V_{OUT} = 3.3 \text{ V}$, $C_{OUT} = 10 \mu\text{F}$

Figure 6-12. Output Noise (V_N) vs Frequency

6.6 Typical Characteristics (continued)

at operating temperature $T_J = 25^\circ\text{C}$, $V_{IN} = V_{OUT(NOM)} + 1.0\text{ V}$ or 2.5 V (whichever is greater), $V_{OUT(\text{typ})} = 3.3\text{ V}$, $I_{OUT} = 1\text{ mA}$, $C_{IN} = 1\text{ }\mu\text{F}$, and $C_{OUT} = 1\text{ }\mu\text{F}$ (unless otherwise noted)

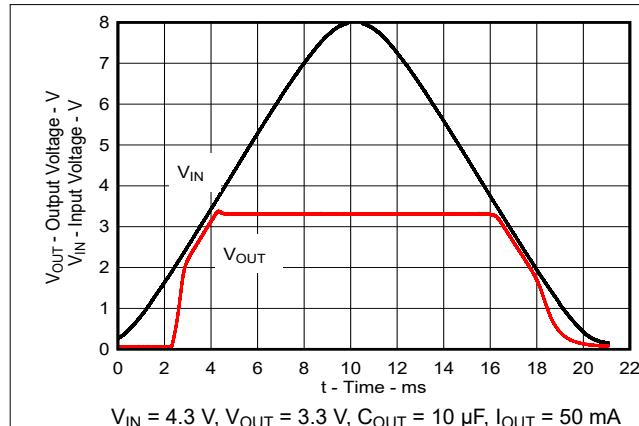


Figure 6-13. Power-Up, Power-Down With V_{IN} Ramp

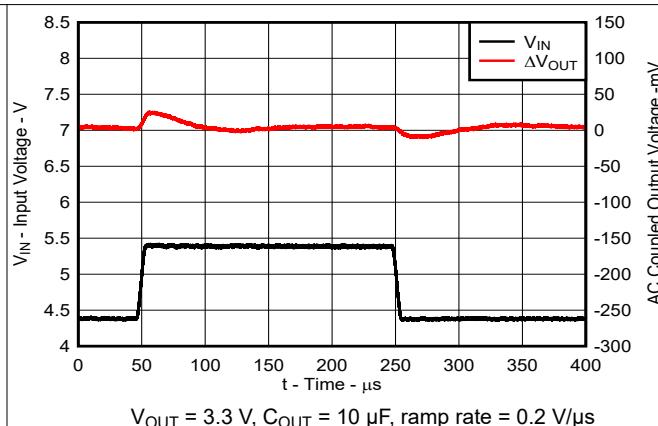


Figure 6-14. V_{IN} Line Transient Response (4.3 V to 5.3 V)

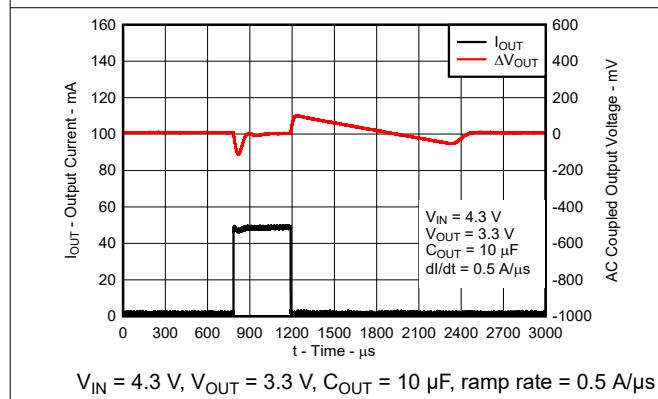


Figure 6-15. I_{OUT} Transient From 1 mA to 50 mA

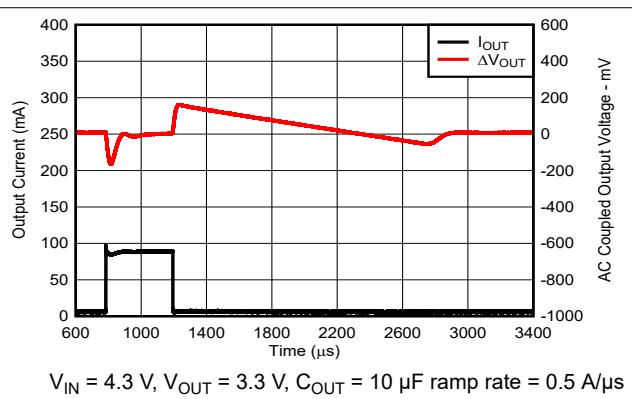


Figure 6-16. I_{OUT} Transient From 1 mA to 80 mA

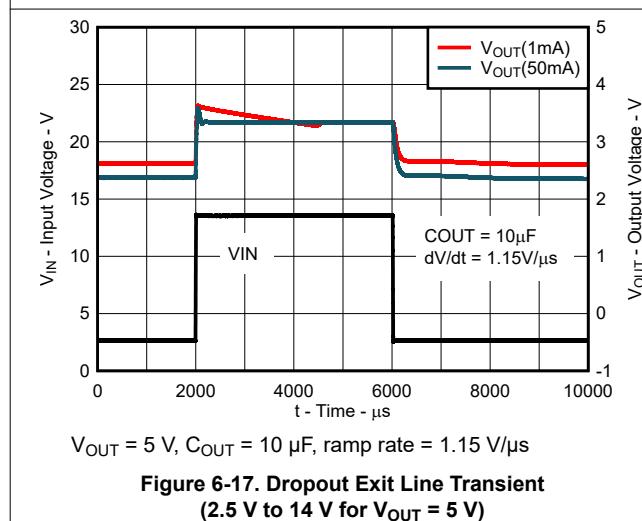


Figure 6-17. Dropout Exit Line Transient (2.5 V to 14 V for $V_{OUT} = 5\text{ V}$)

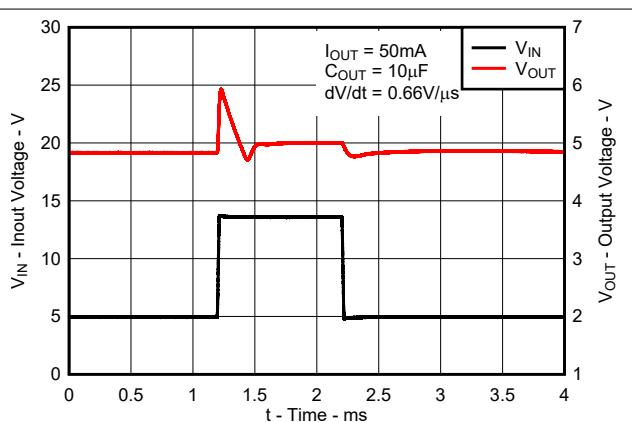


Figure 6-18. V_{IN} Line Transient (5 V to 14 V for $V_{OUT} = 5\text{ V}$)

7 Detailed Description

7.1 Overview

The TLV709 low-dropout regulator (LDO) consumes only 3.2 μ A (typ) of quiescent current across the entire output current range, while offering a wide input voltage range and low-dropout voltage in small packaging. The device, which operates over an input range of 2.5 V to 30 V, is stable with any output capacitor greater than or equal to 1 μ F. The low quiescent current across the complete load current range makes the TLV709 a great choice for powering battery-operated applications. The TLV709 has an internal soft-start to control inrush current into the output capacitor. This LDO also has overcurrent protection during a load-short or fault condition on the output.

7.2 Functional Block Diagrams

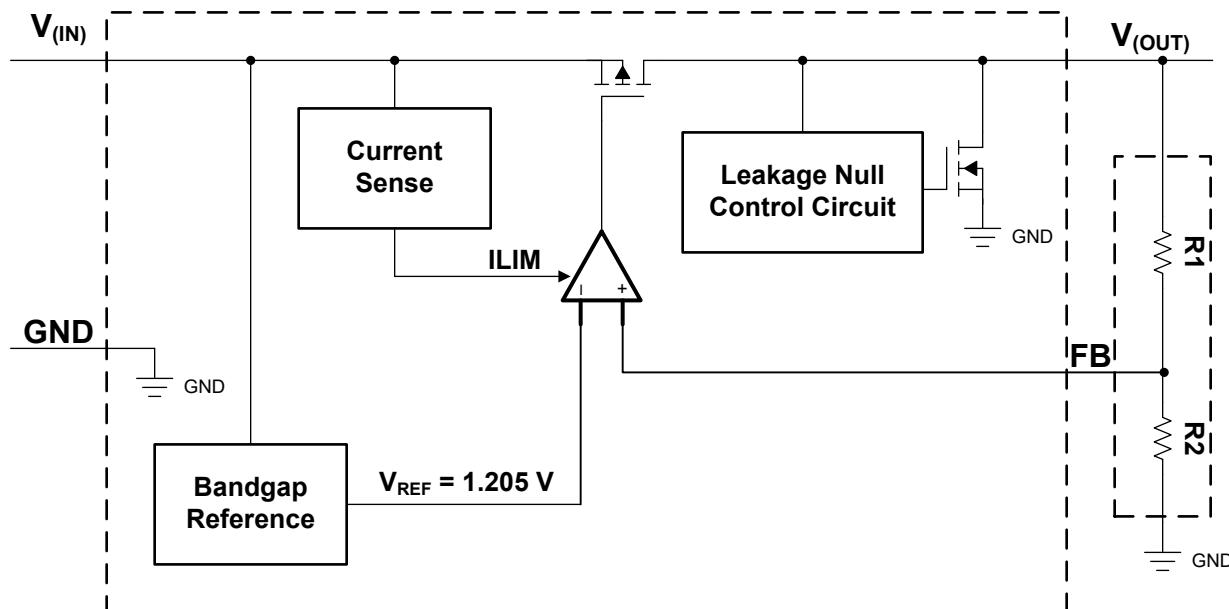


Figure 7-1. Functional Block Diagram: Adjustable Version

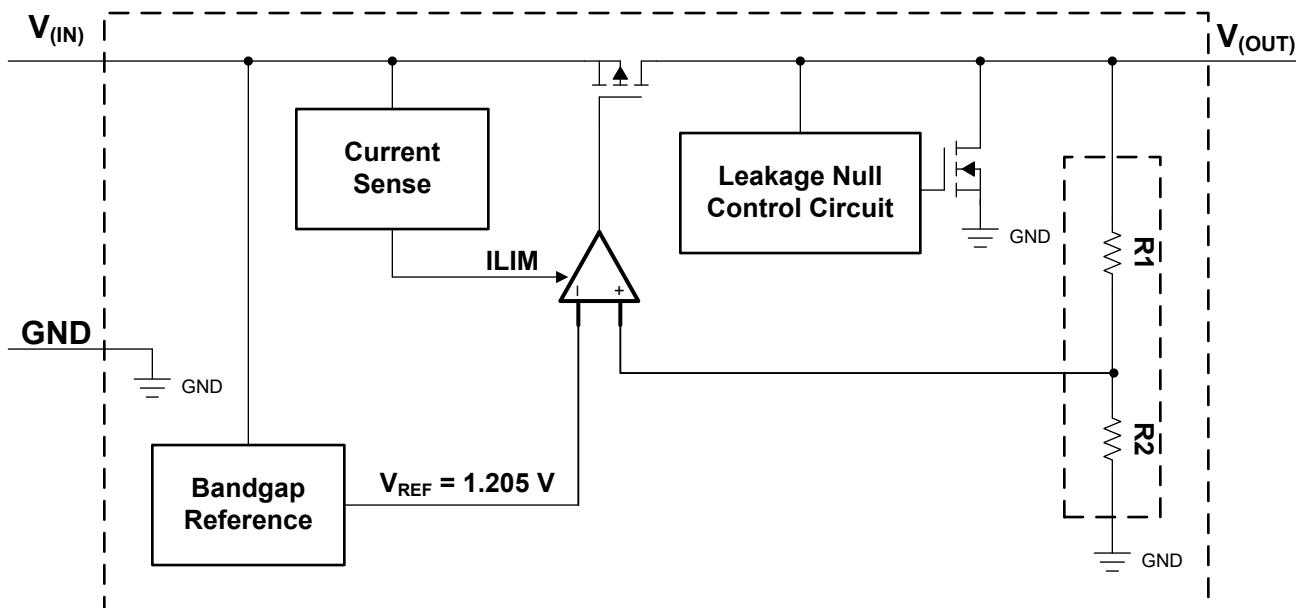


Figure 7-2. Functional Block Diagram: Fixed Version

7.3 Feature Description

7.3.1 Wide Supply Range

This device has an operational input supply range of 2.5 V to 30 V, allowing for a wide range of applications. This wide supply range is designed for applications that have either large transients or high DC voltage supplies.

7.3.2 Low Quiescent Current

This device only requires 3.2 μ A (typical) of quiescent current across the complete load current range (0 mA to 150 mA) at room temperature and 4.8 μ A (max) across the temperature range of -40°C to $+125^{\circ}\text{C}$.

7.3.3 Dropout Voltage (V_{DO})

Dropout voltage (V_{DO}) is defined as the input voltage minus the output voltage ($V_{\text{IN}} - V_{\text{OUT}}$) at the rated output current (I_{RATED}), where the pass transistor is fully on. I_{RATED} is the maximum I_{OUT} listed in the [Recommended Operating Conditions](#) table. In dropout operation, the pass transistor is in the ohmic or triode region of operation, and acts as a switch. The dropout voltage indirectly specifies a minimum input voltage greater than the nominal programmed output voltage at which the output voltage is expected to stay in regulation. If the input voltage falls to less than the value required to maintain output regulation, then the output voltage falls as well.

For a CMOS regulator, the dropout voltage is determined by the drain-source, on-state resistance ($R_{\text{DS(ON)}}$) of the pass transistor. Therefore, if the linear regulator operates at less than the rated current, the dropout voltage for that current scales accordingly. Use [Equation 1](#) to calculate the $R_{\text{DS(ON)}}$ of the device.

$$R_{\text{DS(ON)}} = \frac{V_{\text{DO}}}{I_{\text{RATED}}} \quad (1)$$

7.3.4 Current Limit

The device has an internal current limit circuit that protects the regulator during transient high-load current faults or shorting events. The current limit is a brick-wall scheme. In a high-load current fault, the brick-wall scheme limits the output current to the current limit (I_{CL}). I_{CL} is listed in the [Electrical Characteristics](#) table.

The output voltage is not regulated when the device is in current limit. When a current limit event occurs, the device begins to heat up because of the increase in power dissipation. When the device is in brick-wall current limit, the pass transistor dissipates power $[(V_{\text{IN}} - V_{\text{OUT}}) \times I_{\text{CL}}]$. For more information on current limits, see the [Know Your Limits](#) application note.

Figure 7-3 shows a diagram of the current limit.

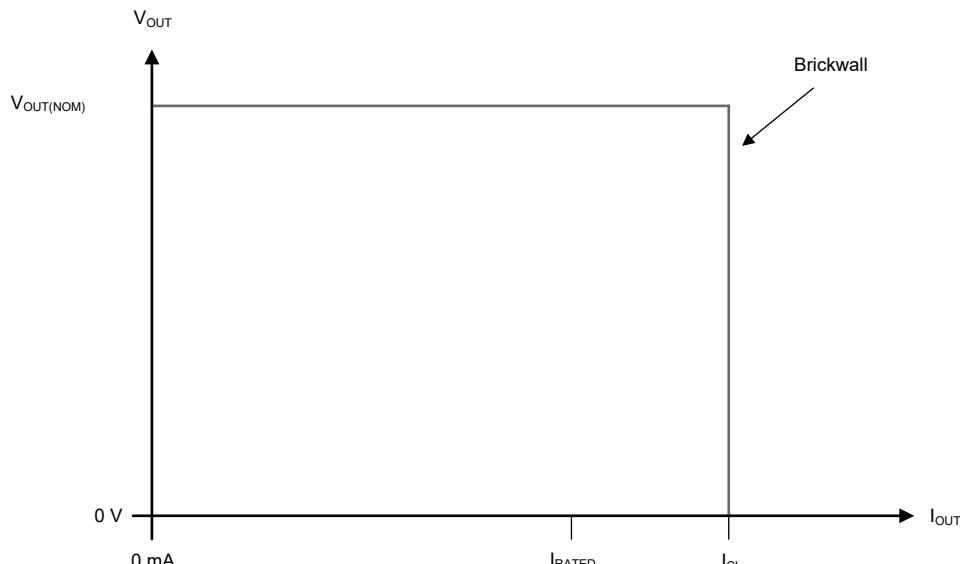


Figure 7-3. Current Limit

7.3.5 Leakage Null Control Circuit

This device has a built-in leakage-null control circuit. At high temperatures, pass-transistor leakage increases and starts impacting the V_{OUT} accuracy at no-load ($I_{OUT} = 0$ mA) conditions. This leakage becomes more aggravated with higher headroom across the LDO ($V_{IN} - V_{OUT}$). The TLV709 has a built-in leakage-null control circuit that detects pass-transistor leakage and provides a ground discharge path for the leakage. This circuitry helps the TLV709 maintain much tighter V_{OUT} accuracy across wide V_{IN} and temperature (-40°C to $+125^{\circ}\text{C}$) ranges.

7.4 Device Functional Modes

Table 7-1 provides a quick comparison between the normal and dropout modes of operation.

Table 7-1. Device Functional Mode Comparison

| OPERATING MODE | PARAMETER | |
|----------------|----------------------------------|--------------------|
| | V_{IN} | I_{OUT} |
| Normal | $V_{IN} > V_{OUT(nom)} + V_{DO}$ | $I_{OUT} < I_{CL}$ |
| Dropout | $V_{IN} < V_{OUT(nom)} + V_{DO}$ | $I_{OUT} < I_{CL}$ |

7.4.1 Normal Operation

The device regulates to the nominal output voltage under the following conditions:

- The input voltage is greater than the nominal output voltage plus the dropout voltage ($V_{OUT(nom)} + V_{DO}$)
- The output current is less than the current limit ($I_{OUT} < I_{CL}$)
- The device junction temperature is greater than -40°C and less than $+125^{\circ}\text{C}$

7.4.2 Dropout Operation

If the input voltage is lower than the nominal output voltage plus the specified dropout voltage, but all other conditions are met for normal operation, the device operates in dropout mode. In this mode, the output voltage tracks the input voltage. During this mode, the transient performance of the device becomes significantly degraded because the pass transistor is in the ohmic or triode region, and acts as a switch. Line or load transients in dropout can result in large output voltage deviations.

When the device is in a steady dropout state (defined as when the device is in dropout, $V_{IN} < V_{OUT(NOM)} + V_{DO}$, directly after being in a normal regulation state, but *not* during start up), the pass transistor is driven into the ohmic or triode region. When the input voltage returns to a value greater than or equal to the nominal output voltage plus the dropout voltage ($V_{OUT(NOM)} + V_{DO}$), the output voltage can overshoot for a short period of time while the device pulls the pass transistor back into the linear region.

8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The TLV709 LDO regulator is a good choice for battery-powered applications and is a good supply for low-power microcontrollers, such as the [MSP430](#), because of the device low I_Q performance across load current range. The ultra-low-supply current of the TLV709 maximizes efficiency at light loads and the high input voltage range and flexibility of output voltage selection in adjustable configuration and fixed output levels makes the device optimal as a supply in building automation and power tools.

8.2 Typical Application

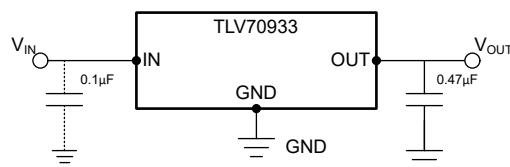


Figure 8-1. Typical Application Circuit (Fixed-Voltage Version)

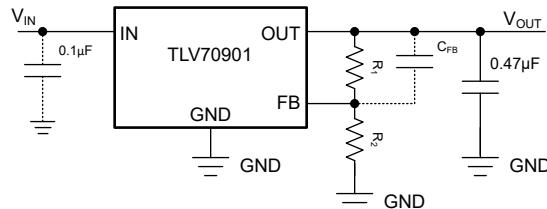


Figure 8-2. TLV70901 Adjustable LDO Regulator Programming

NOTE: Dotted lines indicate an optional input capacitor. See the [Recommended Operating Conditions](#) table and the [Input and Output Capacitor Requirements](#) section.

Table 8-1. Adjustable Output Voltage for Resistors R1 and R2

| OUTPUT VOLTAGE (V) | R1 (MΩ) | R2 (MΩ) |
|--------------------|---------|---------|
| 1.8 | 0.499 | 1 |
| 2.8 | 1.33 | 1 |
| 5.0 | 3.16 | 1 |

8.2.1 Design Requirements

Table 8-2 summarizes the design requirements for Figure 8-1.

Table 8-2. Design Parameters

| PARAMETER | DESIGN REQUIREMENT |
|----------------|--------------------|
| Input voltage | 12 V |
| Output voltage | 3.3 V |
| Output current | 100 mA |

8.2.2 Detailed Design Procedure

8.2.2.1 Setting V_{OUT} for the TLV70901 Adjustable LDO

As illustrated in [Figure 8-2](#), the TLV709 contains an adjustable version (the TLV70901) that sets the output voltage using an external resistor divider. The output voltage operating range is 1.2 V to 28 V, and is calculated using:

$$V_{OUT} = V_{REF} \times \left(1 + \frac{R1}{R2}\right) \quad (2)$$

where:

- $V_{REF} = 1.205$ V (typical)

Choose resistors R1 and R2 to allow approximately 1.5 μ A of current through the resistor divider. Lower value resistors can be used for improved noise performance, but consume more power. Avoid higher resistor values because leakage current into or out of FB across R1 / R2 creates an offset voltage that is proportional to V_{OUT} divided by V_{REF} . The recommended design procedure is to choose $R2 = 1\text{ M}\Omega$ to set the divider current at 1.5 μ A, and then calculate R1 using [Equation 3](#):

$$R1 = \left(\frac{V_{OUT}}{V_{REF}} - 1\right) \times R2 \quad (3)$$

[Figure 8-2](#) depicts this configuration.

8.2.2.2 External Capacitor Requirements

The device is designed to be stable using low equivalent series resistance (ESR) ceramic capacitors at the input and output. Multilayer ceramic capacitors have become the industry standard for these types of applications and are recommended, but must be used with good judgment. Ceramic capacitors that employ X7R-, X5R-, and C0G-rated dielectric materials provide relatively good capacitive stability across temperature, whereas the use of Y5V-rated capacitors is discouraged because of large variations in capacitance.

Regardless of the ceramic capacitor type selected, the effective capacitance varies with operating voltage and temperature. Generally, expect the effective capacitance to decrease by as much as 50%. The input and output capacitors listed in the [Recommended Operating Conditions](#) table account for an effective capacitance of approximately 50% of the nominal value.

8.2.2.3 Input and Output Capacitor Requirements

Although an input capacitor is not required for stability, good analog design practice is to connect a capacitor from IN to GND. This capacitor counteracts reactive input sources and improves transient response, input ripple, and PSRR. Use an input capacitor if the source impedance is more than 0.5 Ω . A higher value capacitor can be necessary if large, fast rise-time load or line transients are anticipated or if the device is located several inches from the input power source.

Dynamic performance of the device is improved by using a larger output capacitor. The TLV709 requires an output capacitor of 1 μ F or larger (0.47 μ F or larger capacitance) for stability and an equivalent series resistance (ESR) between 0.001 Ω and 1 Ω . For best transient performance, use X5R- and X7R-type ceramic capacitors because these capacitors have minimal variation in value and ESR over temperature. When choosing a capacitor for a specific application, be mindful of the DC bias characteristics for the capacitor. Higher output voltages cause a significant derating of the capacitor. Use an output capacitor within the range specified in the [Recommended Operating Conditions](#) table for stability.

8.2.2.4 Reverse Current

Excessive reverse current can damage this device. Reverse current flows through the intrinsic body diode of the PMOS pass transistor instead of the normal conducting channel. At high magnitudes, this current flow degrades the long-term reliability of the device.

Conditions where reverse current can occur are outlined in this section, all of which can exceed the absolute maximum rating of $V_{OUT} \leq V_{IN} + 0.3$ V. These conditions are:

- If the device has a large C_{OUT} and the input supply collapses with little or no load current
- The output is biased when the input supply is not established
- The output is biased above the input supply

If reverse current flow is expected in the application, use external protection to protect the device. Reverse current is not limited in the device, so external limiting is required if extended reverse voltage operation is anticipated. Limit reverse current to 5% or less of the rated output current of the device in the event this current cannot be avoided.

Figure 8-3 shows one approach for protecting the device.

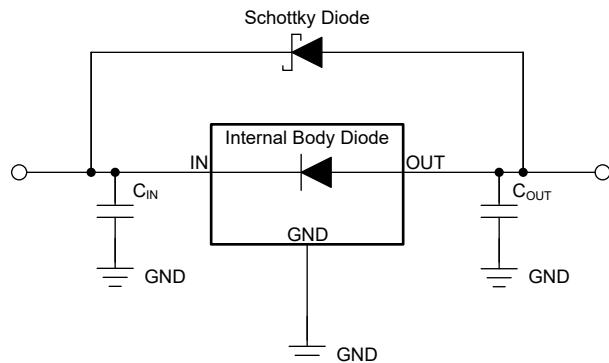


Figure 8-3. Example Circuit for Reverse Current Protection Using a Schottky Diode

8.2.2.5 Feed-Forward Capacitor (C_{FF})

For the adjustable-voltage version device, a feed-forward capacitor (C_{FF}) can be connected from the OUT pin to the FB pin. C_{FF} improves transient, noise, and PSRR performance, but is not required for regulator stability. Recommended C_{FF} values are listed in the [Recommended Operating Conditions](#) table. A higher capacitance C_{FF} can be used; however, the start-up time increases. For a detailed description of C_{FF} tradeoffs, see the [Pros and Cons of Using a Feedforward Capacitor with a Low-Dropout Regulator](#) application note.

C_{FF} and R_1 form a zero in the loop gain at frequency f_Z , while C_{FF} , R_1 , and R_2 form a pole in the loop gain at frequency f_P . C_{FF} zero and pole frequencies can be calculated from the following equations:

$$f_Z = 1 / (2 \times \pi \times C_{FF} \times R_1) \quad (4)$$

$$f_P = 1 / (2 \times \pi \times C_{FF} \times (R_1 \parallel R_2)) \quad (5)$$

$C_{FF} \geq 10$ pF is required for stability if the feedback divider current is less than 5 μ A. [Equation 6](#) calculates the feedback divider current.

$$I_{FB_Divider} = V_{OUT} / (R_1 + R_2) \quad (6)$$

To avoid start-up time increases from C_{FF} , limit the product $C_{FF} \times R_1 < 50$ μ s.

For an output voltage of 1.205 V with the FB pin tied to the OUT pin, no C_{FF} is used.

8.2.2.6 Power Dissipation (P_D)

Circuit reliability requires consideration of the device power dissipation, location of the circuit on the printed circuit board (PCB), and correct sizing of the thermal plane. The PCB area around the regulator must have few or no other heat-generating devices that cause added thermal stress.

To first-order approximation, power dissipation in the regulator depends on the input-to-output voltage difference and load conditions. The following equation calculates power dissipation (P_D).

$$P_D = (V_{IN} - V_{OUT}) \times I_{OUT} \quad (7)$$

Note

Power dissipation can be minimized, and therefore greater efficiency can be achieved, by correct selection of the system voltage rails. For the lowest power dissipation, use the minimum input voltage required for correct output regulation.

For devices with a thermal pad, the primary heat conduction path for the device package is through the thermal pad to the PCB. Solder the thermal pad to a copper pad area under the device. This pad area must contain an array of plated vias that conduct heat to additional copper planes for increased heat dissipation.

The maximum power dissipation determines the maximum allowable ambient temperature (T_A) for the device. According to the following equation, power dissipation and junction temperature are most often related by the junction-to-ambient thermal resistance ($R_{\theta JA}$) of the combined PCB and device package and the temperature of the ambient air (T_A).

$$T_J = T_A + (R_{\theta JA} \times P_D) \quad (8)$$

Thermal resistance ($R_{\theta JA}$) is highly dependent on the heat-spreading capability built into the particular PCB design, and therefore varies according to the total copper area, copper weight, and location of the planes. The junction-to-ambient thermal resistance listed in the [Thermal Information](#) table is determined by the JEDEC standard PCB and copper-spreading area, and is used as a relative measure of package thermal performance. As mentioned in the [An empirical analysis of the impact of board layout on LDO thermal performance application note](#), $R_{\theta JA}$ can be improved by 35% to 55% compared to the [Thermal Information](#) table value with the PCB board layout optimization.

8.2.2.7 Estimating Junction Temperature

The JEDEC standard now recommends the use of psi (Ψ) thermal metrics to estimate the junction temperatures of the linear regulator when in-circuit on a typical PCB board application. These metrics are not thermal resistance parameters and instead offer a practical and relative way to estimate junction temperature. These psi metrics are determined to be significantly independent of the copper area available for heat-spreading. The [Thermal Information](#) table lists the primary thermal metrics, which are the junction-to-top characterization parameter (Ψ_{JT}) and junction-to-board characterization parameter (Ψ_{JB}). These parameters provide two methods for calculating the junction temperature (T_J), as described in the following equations. Use the junction-to-top characterization parameter (Ψ_{JT}) with the temperature at the center-top of device package (T_T) to calculate the junction temperature. Use the junction-to-board characterization parameter (Ψ_{JB}) with the PCB surface temperature 1 mm from the device package (T_B) to calculate the junction temperature.

$$T_J = T_T + \Psi_{JT} \times P_D \quad (9)$$

where:

- P_D is the dissipated power
- T_T is the temperature at the center-top of the device package

$$T_J = T_B + \psi_{JB} \times P_D \quad (10)$$

where:

- T_B is the PCB surface temperature measured 1 mm from the device package and centered on the package edge

For detailed information on the thermal metrics and how to use them, see the [Semiconductor and IC Package Thermal Metrics application note](#).

8.3 Best Design Practices

Place at least one 0.47- μ F capacitor as close as possible to the OUT and GND pins of the regulator.

Do not connect the output capacitor to the regulator using a long, thin trace.

Connect an input capacitor as close as possible to the IN and GND pins of the regulator for best performance.

Do not exceed the absolute maximum ratings.

8.4 Power Supply Recommendations

The TLV709 is designed to operate from an input voltage supply range between 2.5 V and 30 V. The input voltage range provides adequate headroom in order for the device to have a regulated output. If the input supply is noisy, additional input capacitors with low ESR can help improve the output noise performance.

8.5 Layout

8.5.1 Layout Guidelines

For best overall performance, place all circuit components on the same side of the printed circuit board (PCB) and as near as practical to the respective LDO pin connections. Place ground return connections for the input and output capacitors as close to the GND pin as possible, using wide, component-side, copper planes. Do not use vias and long traces to create LDO circuit connections to the input capacitor, output capacitor, or the resistor divider because this practice negatively affects system performance. This grounding and layout scheme minimizes inductive parasitics, and thereby reduces load current transients, minimizes noise, and increases circuit stability. A ground reference plane is also recommended and is either embedded in the PCB or located on the bottom side of the PCB opposite the components. This reference plane serves to assure accuracy of the output voltage and shield the LDO from noise.

8.5.1.1 Power Dissipation

To ensure reliable operation, worst-case junction temperature must not exceed 125°C. This restriction limits the power dissipation the regulator can handle in any given application. To ensure the junction temperature is within acceptable limits, calculate the maximum allowable dissipation, $P_{D(max)}$, and the actual dissipation, P_D , which must be less than or equal to $P_{D(max)}$.

[Equation 11](#) determines the maximum-power-dissipation limit:

$$P_{D(max)} = \frac{T_J \max - T_A}{R_{\theta JA}} \quad (11)$$

where:

- $T_J \max$ is the maximum allowable junction temperature
- $R_{\theta JA}$ is the thermal resistance junction-to-ambient for the package (see the [Thermal Information](#) table)
- T_A is the ambient temperature

[Equation 12](#) calculates the regulator dissipation:

$$P_D = (V_{IN} - V_{OUT}) \times I_{OUT} \quad (12)$$

8.5.2 Layout ExamplesFeedback

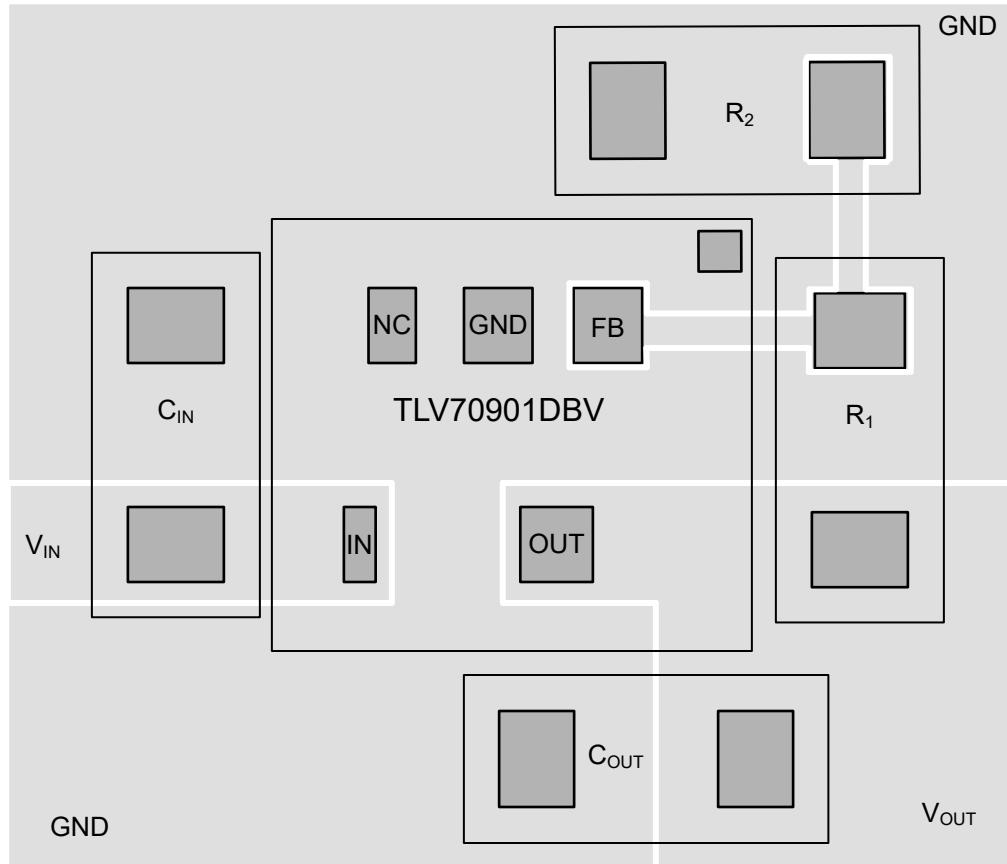


Figure 8-4. Example Layout for the TLV70901DBV

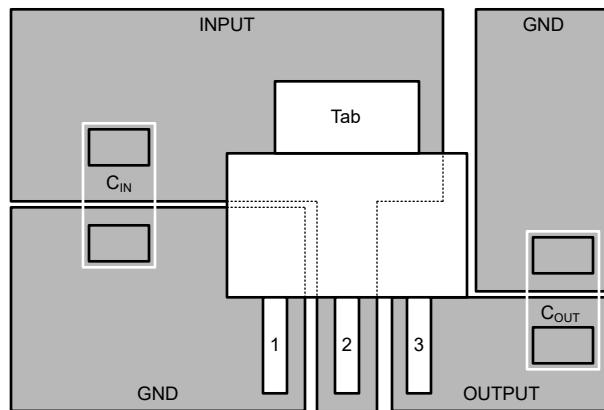


Figure 8-5. Example Layout for the TLV709xxPK (IN Tab)

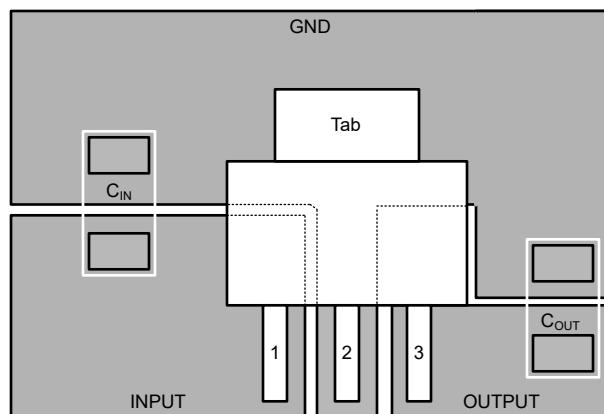


Figure 8-6. Example Layout for the TLV709AxxPK (GND Tab)

9 Device and Documentation Support

9.1 Device Support

9.1.1 Development Support

9.1.1.1 Evaluation Module

An evaluation module (EVM) is available to assist in the initial circuit performance evaluation using the TLV709. The [TPS71533EVM evaluation module](#) (and related [user's guide](#)) can be requested at the TI website through the product folders or purchased directly from [the TI eStore](#).

9.1.1.2 Spice Models

Computer simulation of circuit performance using SPICE is often useful when analyzing the performance of analog circuits and systems. A SPICE model for the TLV709 is available through the product folders under *Tools & Software*.

9.1.2 Device Nomenclature

Table 9-1. Device Nomenclature⁽¹⁾

| PRODUCT | V _{OUT} |
|---------------|---|
| TLV709AxxDBVz | In the SOT-23 (DBV) package: XX is the nominal output voltage (for example, 33 = 3.3 V, 50 = 50 V, 01 = Adjustable). Z is the package quantity. |
| TLV709xxPKz | In the SOT-89 (PK) package with an IN tab: XX is the nominal output voltage (for example, 33 = 3.3 V, 50 = 50 V). Z is the package quantity. |
| TLV709AxxPKz | In the SOT-89 (PK) package with a GND tab: XX is the nominal output voltage (for example, 33 = 3.3 V, 50 = 50 V). Z is the package quantity. |

- (1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

9.2 Documentation Support

9.2.1 Related Documentation

For related documentation see the following:

- Texas Instruments, [TPS71533EVM LDO Regulator Evaluation Module user guide](#)

9.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](#). Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.4 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

9.5 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

9.6 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.



ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.7 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|-----------------|------|-------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|---------|
| PTLV70933PKR | ACTIVE | SOT-89 | PK | 3 | 3000 | TBD | Call TI | Call TI | -40 to 125 | | Samples |
| PTLV70950PKR | ACTIVE | SOT-89 | PK | 3 | 3000 | TBD | Call TI | Call TI | -40 to 125 | | Samples |
| PTLV709A33DBVR | ACTIVE | SOT-23 | DBV | 5 | 3000 | TBD | Call TI | Call TI | -40 to 125 | | Samples |
| TLV709A01DBVR | ACTIVE | SOT-23 | DBV | 5 | 3000 | RoHS & Green | SN | Level-1-260C-UNLIM | -40 to 125 | 2V8F | Samples |
| TLV709A33DBVR | ACTIVE | SOT-23 | DBV | 5 | 3000 | RoHS & Green | SN | Level-1-260C-UNLIM | -40 to 125 | 2V6F | Samples |
| TLV709A33PKR | ACTIVE | SOT-89 | PK | 3 | 1000 | RoHS & Green | SN | Level-3-260C-168 HR | -40 to 125 | NT | Samples |
| TLV709A50DBVR | ACTIVE | SOT-23 | DBV | 5 | 3000 | RoHS & Green | SN | Level-1-260C-UNLIM | -40 to 125 | 2V7F | Samples |
| TLV709A50PKR | ACTIVE | SOT-89 | PK | 3 | 1000 | RoHS & Green | SN | Level-3-260C-168 HR | -40 to 125 | NW | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

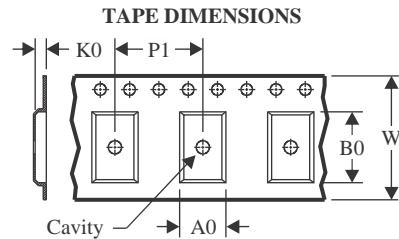
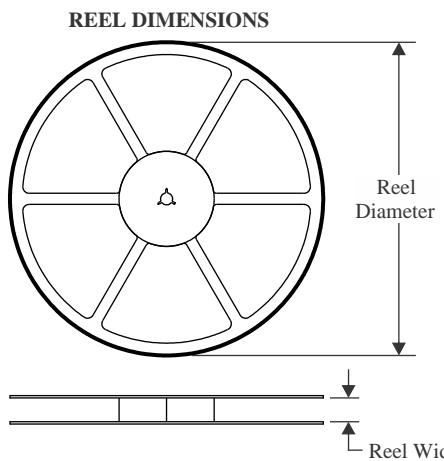
(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

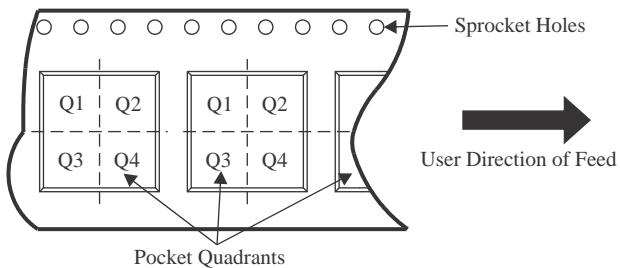
(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

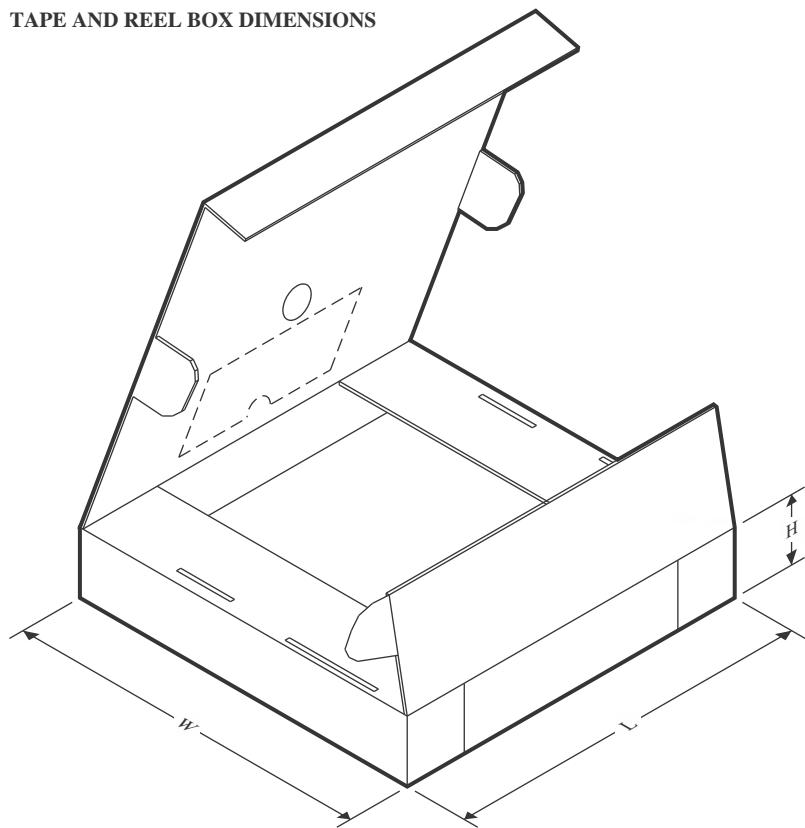
TAPE AND REEL INFORMATION

| | |
|----|---|
| A0 | Dimension designed to accommodate the component width |
| B0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TLV709A01DBVR | SOT-23 | DBV | 5 | 3000 | 180.0 | 8.4 | 3.2 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| TLV709A33DBVR | SOT-23 | DBV | 5 | 3000 | 180.0 | 8.4 | 3.2 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| TLV709A33PKR | SOT-89 | PK | 3 | 1000 | 180.0 | 12.4 | 4.91 | 4.52 | 1.9 | 8.0 | 12.0 | Q3 |
| TLV709A50DBVR | SOT-23 | DBV | 5 | 3000 | 180.0 | 8.4 | 3.2 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| TLV709A50PKR | SOT-89 | PK | 3 | 1000 | 180.0 | 12.4 | 4.91 | 4.52 | 1.9 | 8.0 | 12.0 | Q3 |

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TLV709A01DBVR | SOT-23 | DBV | 5 | 3000 | 210.0 | 185.0 | 35.0 |
| TLV709A33DBVR | SOT-23 | DBV | 5 | 3000 | 210.0 | 185.0 | 35.0 |
| TLV709A33PKR | SOT-89 | PK | 3 | 1000 | 190.0 | 190.0 | 30.0 |
| TLV709A50DBVR | SOT-23 | DBV | 5 | 3000 | 210.0 | 185.0 | 35.0 |
| TLV709A50PKR | SOT-89 | PK | 3 | 1000 | 190.0 | 190.0 | 30.0 |

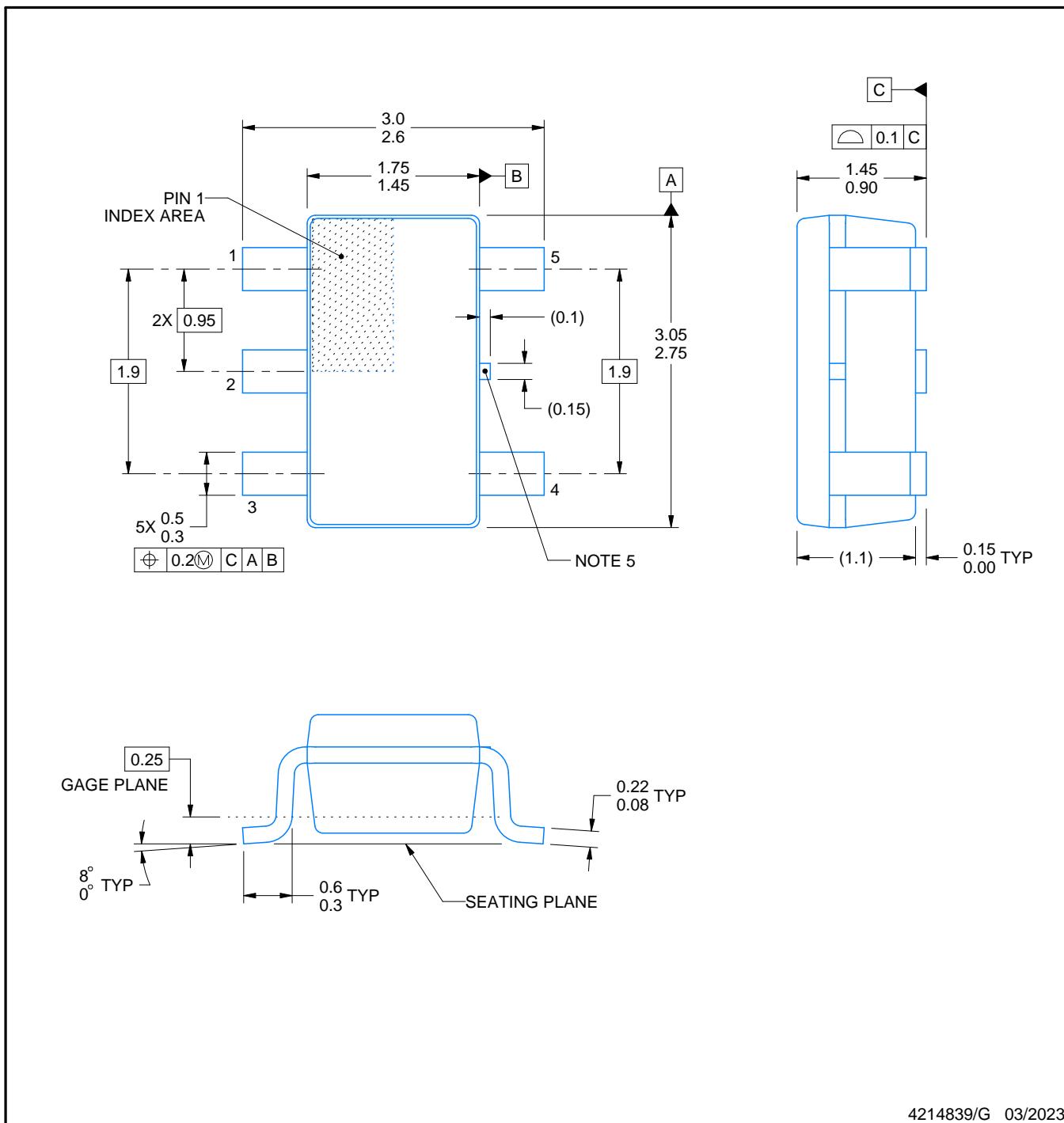
PACKAGE OUTLINE

DBV0005A



SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES:

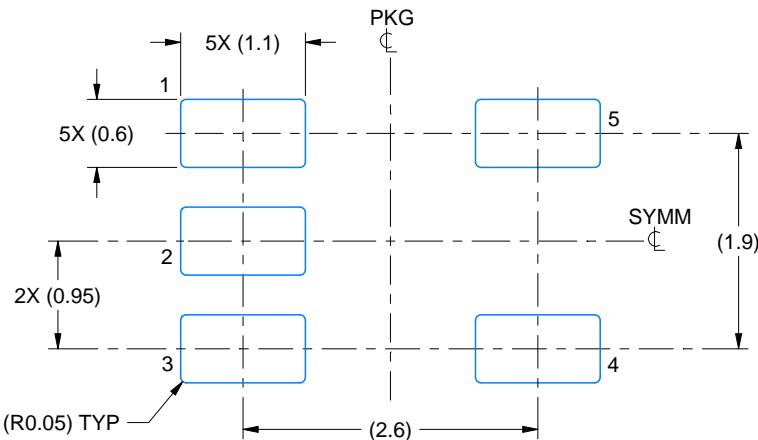
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
5. Support pin may differ or may not be present.

EXAMPLE BOARD LAYOUT

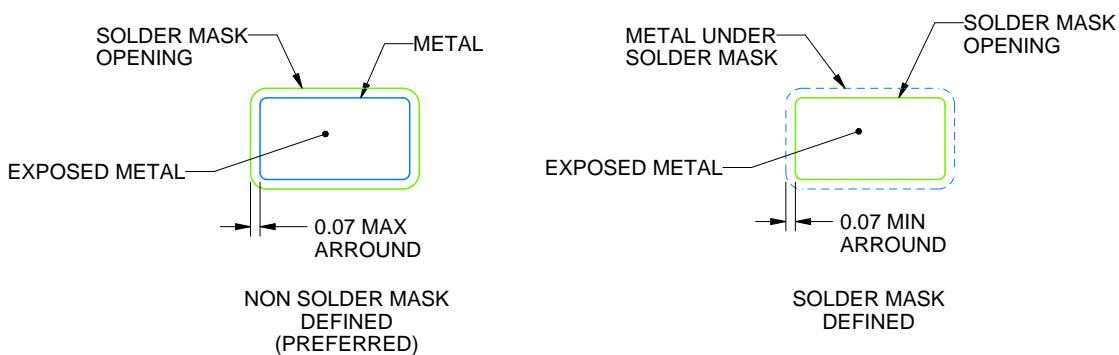
DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4214839/G 03/2023

NOTES: (continued)

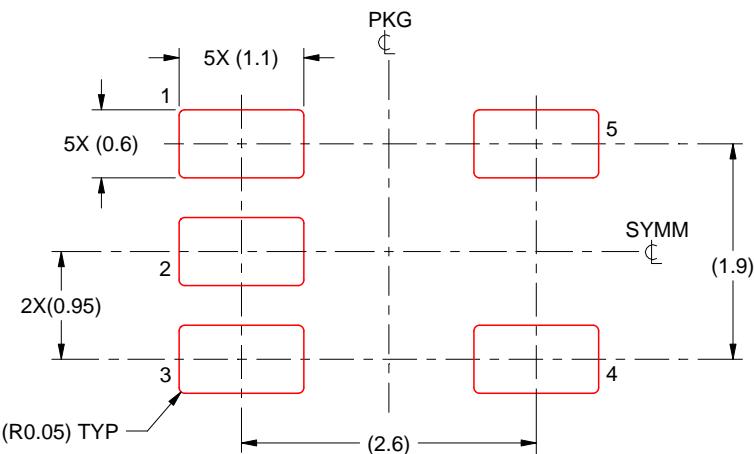
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

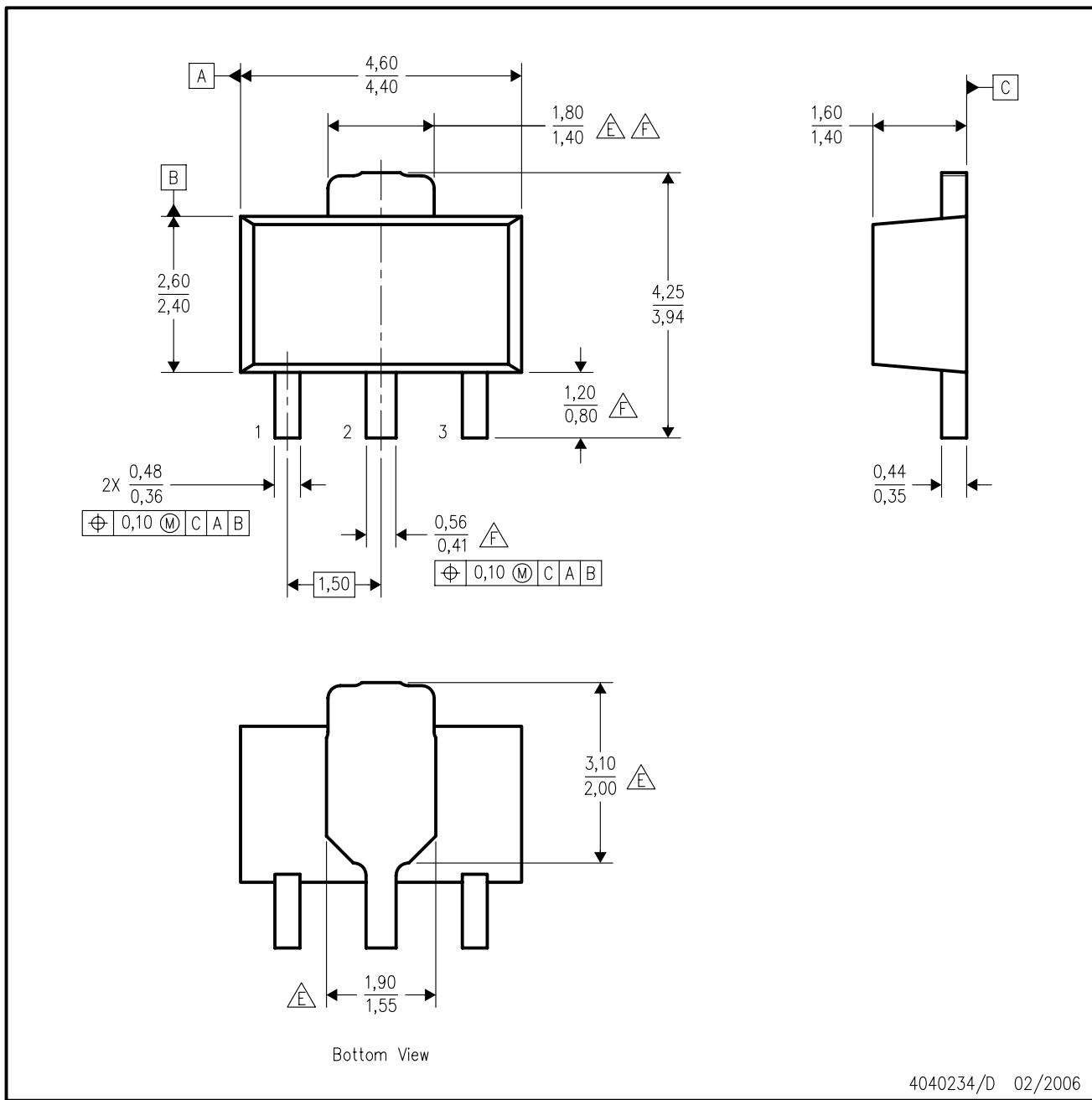
4214839/G 03/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

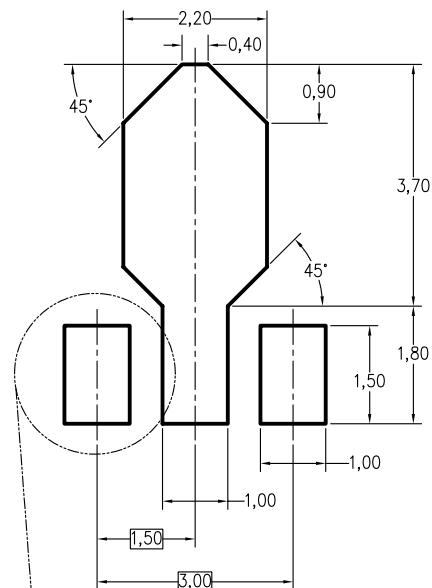
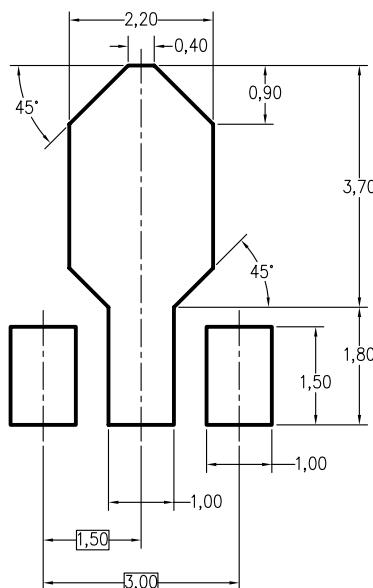
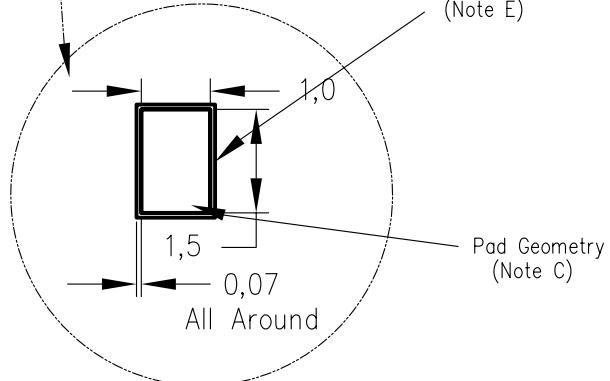
PK (R-PSSO-F3)

PLASTIC SINGLE-IN-LINE PACKAGE



- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. The center lead is in electrical contact with the tab.
 - D. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion not to exceed 0.15 per side.
 - $\triangle E$ Thermal pad contour optional within these dimensions.
 - $\triangle F$ Falls within JEDEC TO-243 variation AA, except minimum lead length, pin 2 minimum lead width, minimum tab width.

PK (R-PDSO-G3)

Example Board Layout
(Note C)Example Stencil Design
(Note D)Non Solder Mask Defined Pad Solder Mask Opening
(Note E)

4208221/A 09/06

- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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